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oducts	Home ▶ 2№5051 (#23269) 2N5051 (#23269)							Related Links		
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	Electrical Rating	Symt	bol Min	Тур	Max	Unit		Sales Contacts RFQ/Samples		
	Collector to Emitter Saturation Voltage	V _{CE(s}	sat)		1.00	V		a campico		
	Movieum Electrical Parine		Suml d	Min	Im Mar	Ilinit				
	Maximum Electrical Rating Breakdown Voltage, Collector-Base (Emitter Ope	n)	Symbol V _{BR(CBO)}		Typ Max 150.00	Unit V				
	Collector Current (dc)	.,	I _C		2.00	A				
	Collector-Emitter Voltage (Base Open)		V _{CEO} 150.00 V							
	Emitter-Base Voltage (Collector Open)		V _{EBO}		6.00	V				
	Power Dissipation, Total		P _T		40.00	W				
	 This part can be found in the following prodution Discretes > Transistors > BJT(BiPolar Junction 7 Non-Radiation Hardened Devices > Transistors > 	Transisto	r) ▶ PNP Trar) 🕨 NPN Transi	stor				

